

EGF1T

Vishay General Semiconductor

Surface Mount Glass Passivated Ultrafast Rectifier





PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

I_{FSM}

t_{rr}

EAS

T_{.1} max.

DO-214BA (GF1)

1.0 A

1300 V

20 A

75 ns

15 mJ

150 °C

DO-21 DO-21 DO-21 DO-21 DO-21 DO-21 DO-21 A 10 - 20 A 10 - 20 DO-21

FEATURES

- Cavity-free glass-passivated junction
- · Ideal for automated placement
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- Avalanche surge energy capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high voltage rectification of photoflash application.

MECHANICAL DATA

Case: DO-214BA, molded plastic over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	EGF1T	UNIT		
Device marking code		ET			
Maximum repetitive peak reverse voltage	V _{RRM}	1300	V		
Maximum RMS voltage	V _{RMS}	910	V		
Maximum DC blocking	V _{DC}	1300	V		
Maximum average forward rectified current	I _{F(AV)}	1.0	А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	20	А		
Non-repetitive avalanche energy at $T_A = 25 \text{ °C}$, $I_{AS} = 1 \text{ A}$, L = 30 mH	E _{AS}	15	mJ		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C		





COMPLIANT

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \degree C$ unless otherwise noted)					
PARAMETER	TEST C	ONDITIONS	SYMBOL	EGF1T	UNIT
Maximum instantaneous forward voltage (1)	1.0 A	T _J = 25 °C	V _F	3.0	V
Maximum DC reverse current ⁽²⁾	V _{RM}	T _J = 25 °C T _J = 125 °C	I _R	5.0 50	μΑ
Typical reverse recovery time	I _F = 0.5 A I _{rr} = 0.25	, I _R =1.0 A, A	t _{rr}	75	ns
Typical junction capacitance	4.0 V, 1 N	lHz	CJ	8.0	pF

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	EGF1T	UNIT	
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}	50 20	°C/W	

Note:

(1) Thermal resistance from junction to ambient and from junction to lead, P.C.B. mounted on 0.95 x 0.95" (24 x 24 mm) copper pad areas

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
EGF1T-E3/67A	0.104	67A	1500	7" diameter plastic tape and reel	
EGF1T-E3/5CA	0.104	5CA	6500	13" diameter plastic tape and reel	
EGF1THE3/67A (1)	0.104	67A	1500	7" diameter plastic tape and reel	
EGF1THE3/5CA ⁽¹⁾	0.104	5CA	6500	13" diameter plastic tape and reel	

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

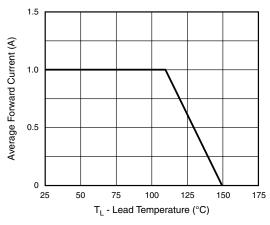


Figure 1. Maximum Forward Current Derating Curve

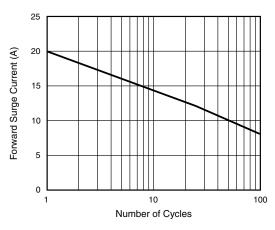


Figure 2. Maximum Non-Repetitive Forward Surge Current



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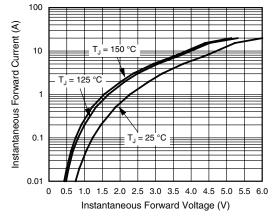
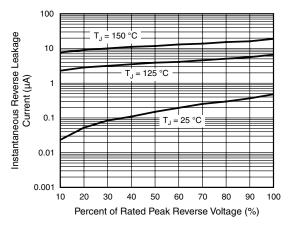
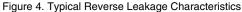


Figure 3. Typical Instantaneous Forward Characteristics





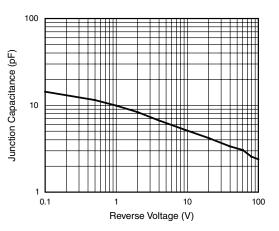


Figure 5. Typical Junction Capacitance Per Leg

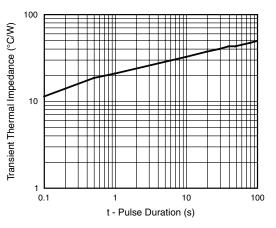
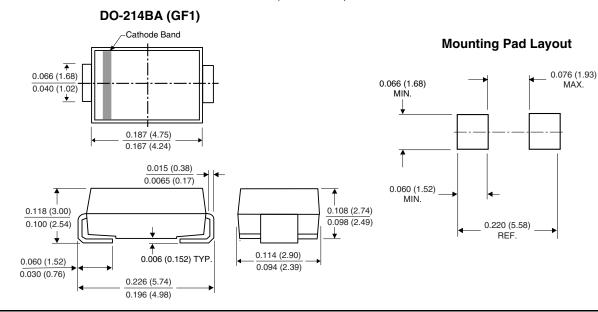


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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